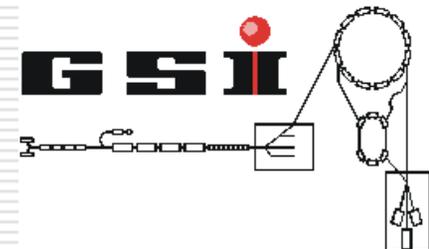


Ideas around the EXL recoil detector

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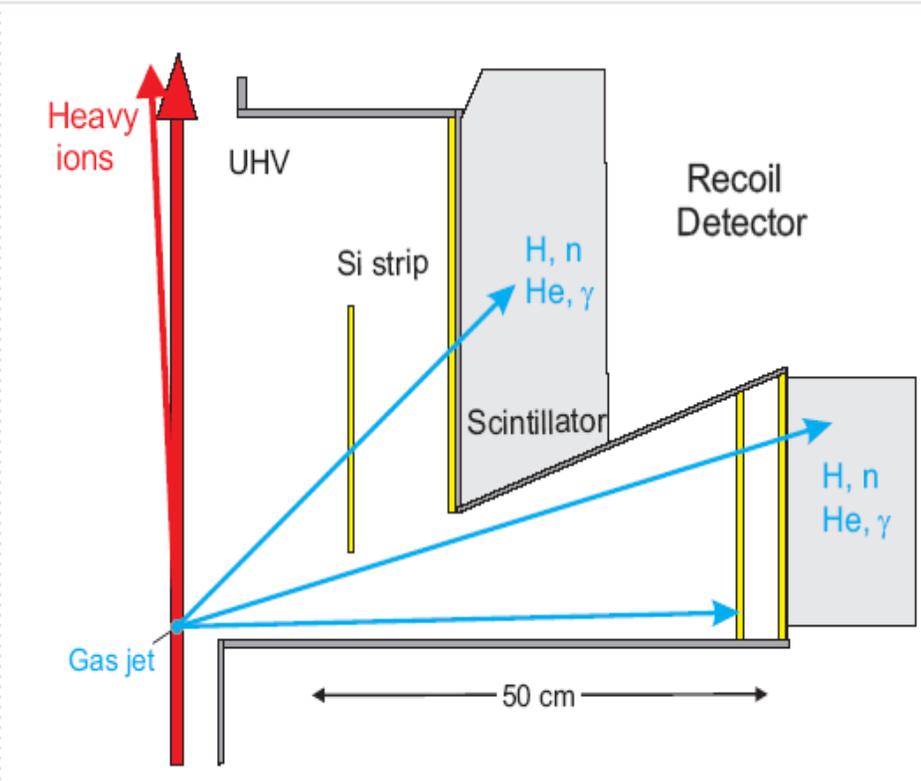
Institut für Kernchemie, Johannes Gutenberg Universität Mainz



Main goals

- ✓ *Elastic scattering*
 - ✓ *Inelastic scattering*
 - ✓ *Transfer reactions*
 - ✓ *Charge-exchange reactions*
 - ✓ *Quasi-free scattering*
 - ✓ As more universal detector as possible
 - ✓ Key parameters – very low energy threshold, high angular and energy resolution
 - ✓ Recoil particles – from (few) 100 keV up to (few) 100 MeV
-

EXL recoil detector



Very preliminary scheme

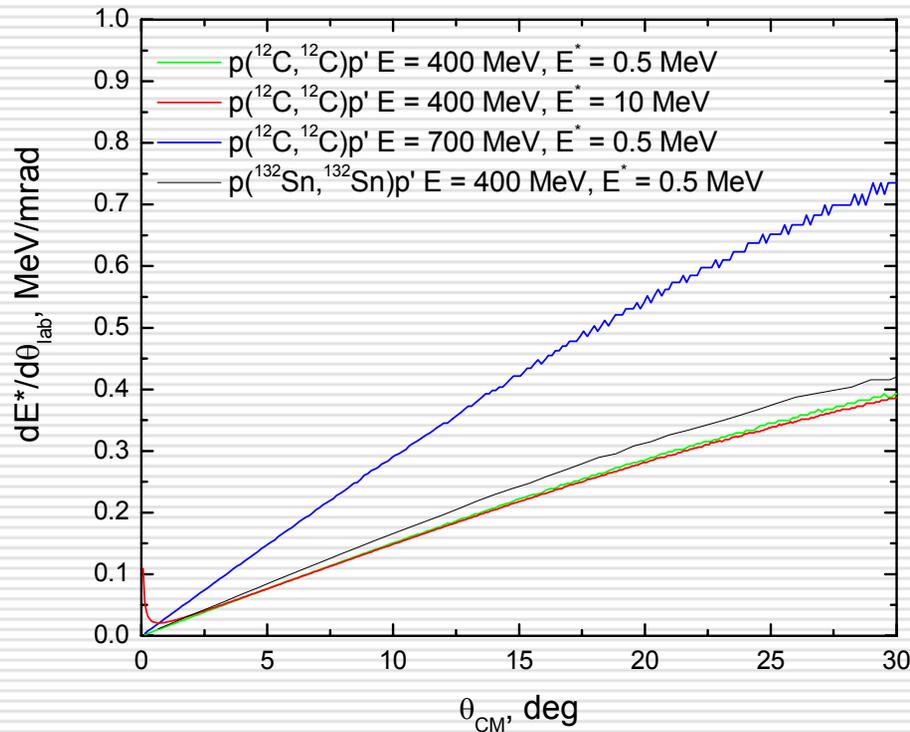
Energy, TOF, angle
Measurements

Part of the setup – in UHV
(10^{-9} - 10^{-11} mbar)

Mostly solid state detectors

Low data rate per single
detector, high – in total

Angular and energy resolution



From kinematics:

$$\Delta E^* < 0.1 \text{ MeV}$$

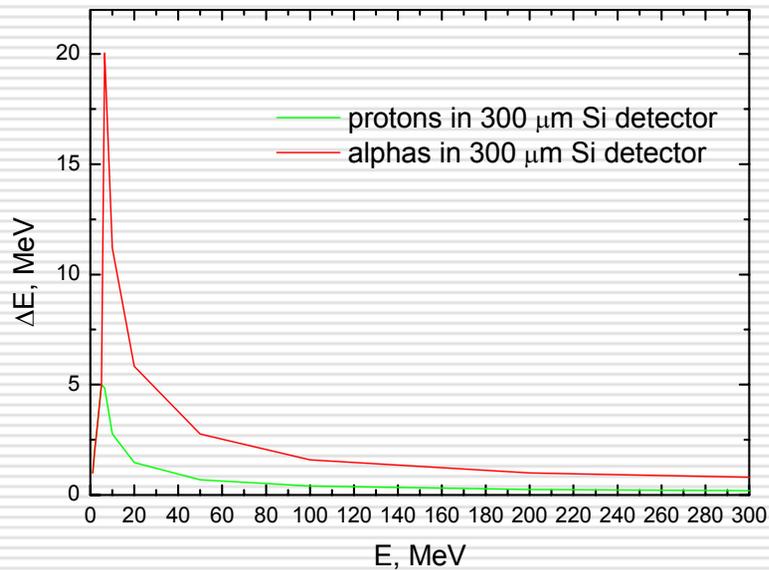
$$\Delta \theta_{\text{CM}} < \text{few mrad}$$

$$\text{for recoils: } \Delta E_{\text{lab}} < 0.1 \text{ MeV}$$

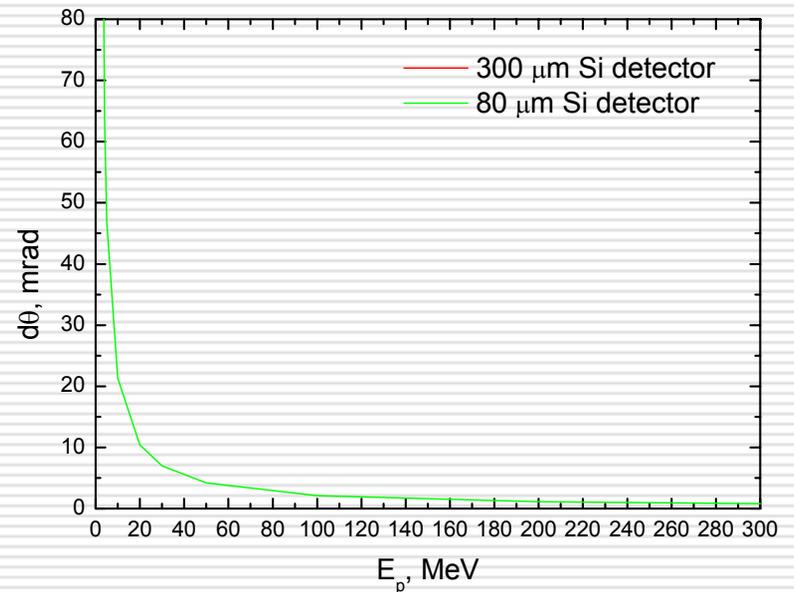
$$\Delta \theta_{\text{lab}} < 1\text{-}2 \text{ mrad}$$

Example of inelastic scattering

Dynamic range and multiple scattering

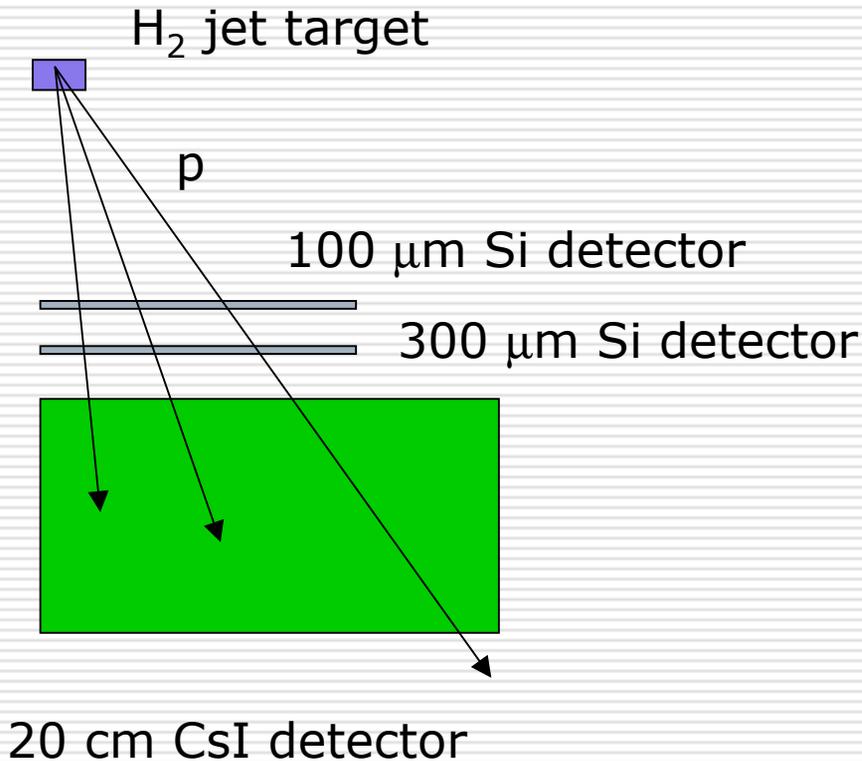


Electronics must have quite high dynamic range – up to 20 MeV for α -particles
Threshold – 50-70 keV (hopefully)
Dynamic range – 1:400



Only one layer of Si for protons with $E < 20$ MeV
Thin detector for the first layer in forward region

Detector geometry – GEANT4



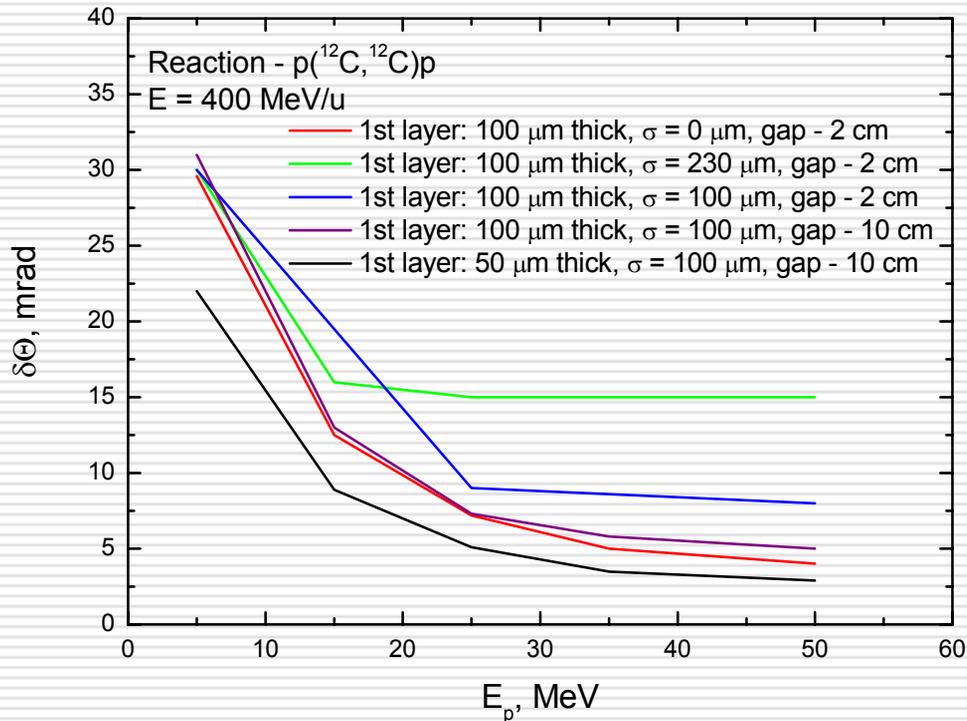
Jet target – Ø 5 mm, 1 mm height

Two layers of Si detectors – 30 and 32 cm from the target

CsI scintillator to measure total energy

Everything is in vacuum

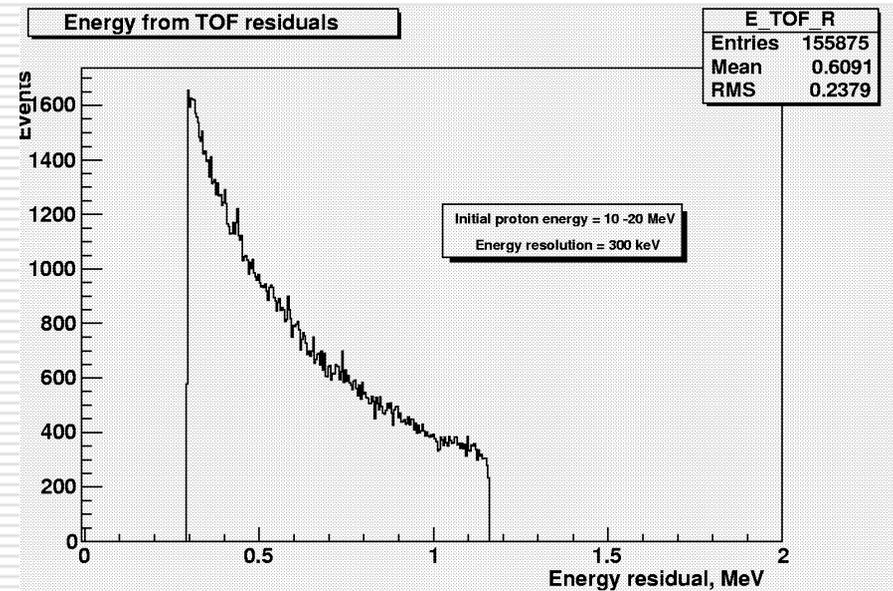
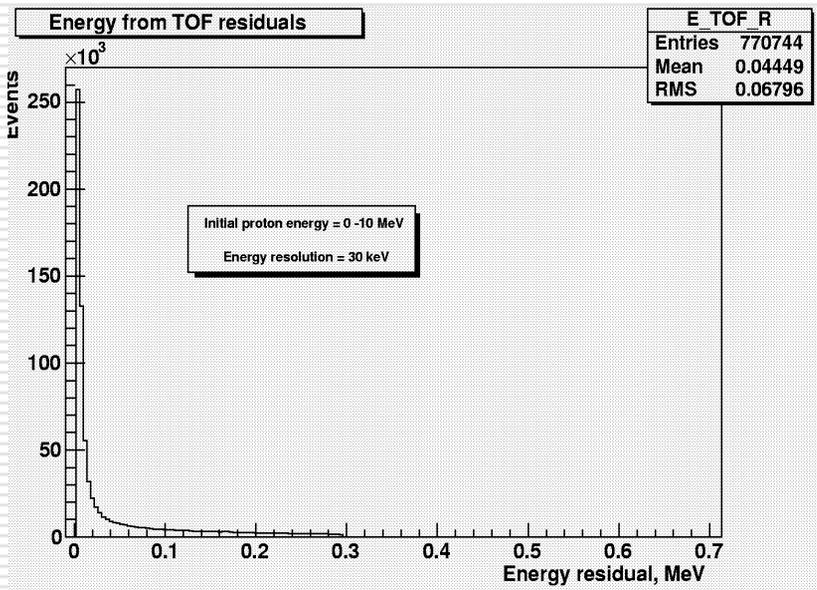
Simulated angular resolution



For $E_p < 20 - 25 \text{ MeV}$ – no first layer, tracking based on the size of interaction point ($< 2 \text{ mm}$) and position resolution of single Si detector

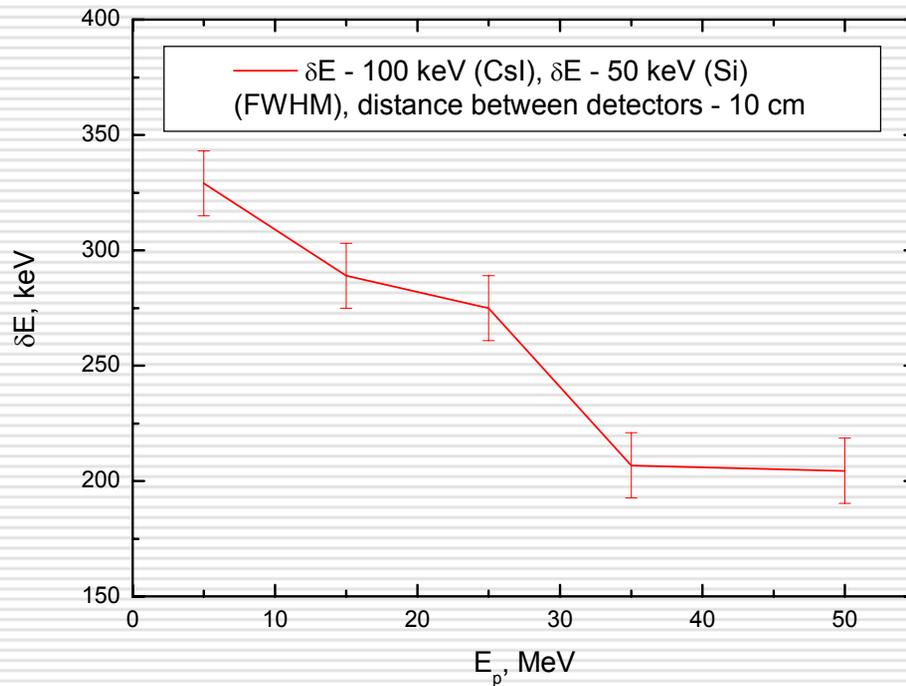
For $E_p > 25 \text{ MeV}$ first layer must be very thin ($50 \mu\text{m}$ or less)

Simulated energy resolution (via TOF)



Time resolution of the detectors is not yet included
Energy via TOF is possible for very slow protons (0 – 10 MeV)

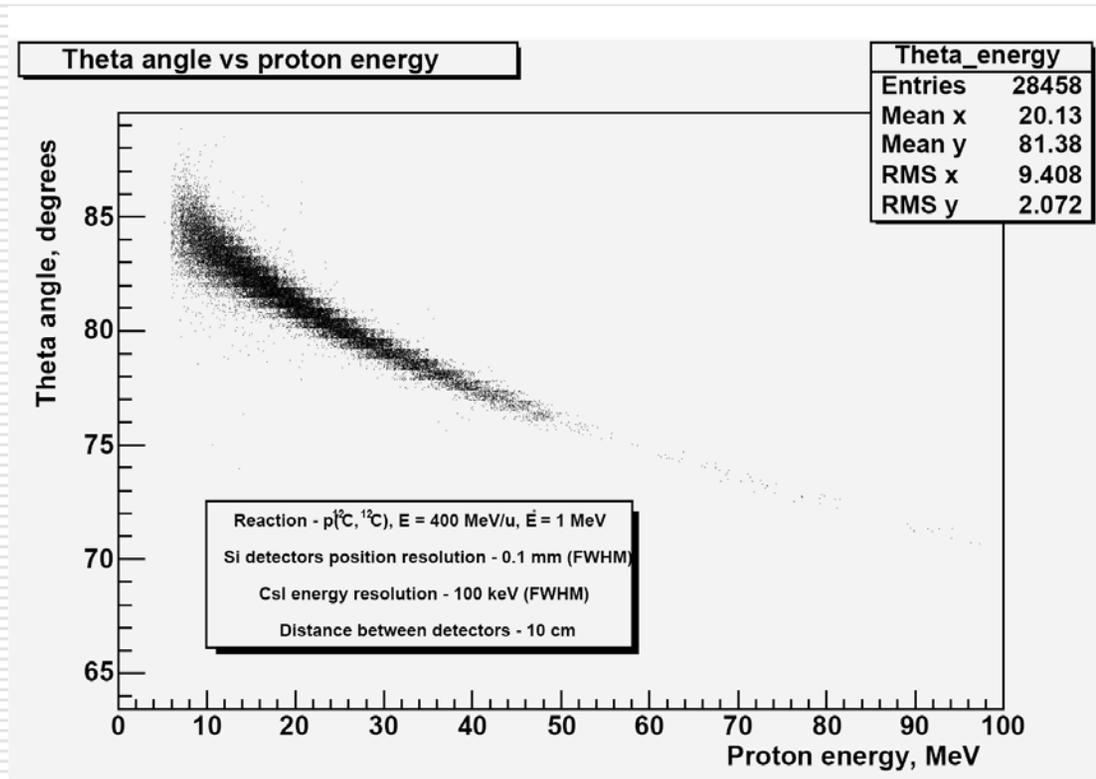
Simulated energy resolution



For $E_p < 20 - 25$ MeV – energy straggling is too high \Rightarrow no first layer

For $E_p > 25$ MeV thing first layer but the energy resolution of all detectors must be very good

Simulated angle – energy correlation

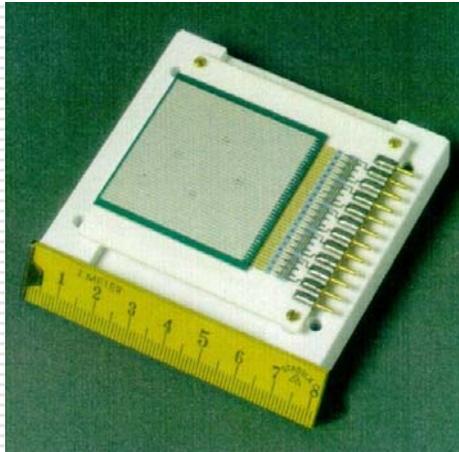


Two types of reactions –
elastic and inelastic
($E^* = 1 \text{ MeV}$) scattering

Simulations – next steps

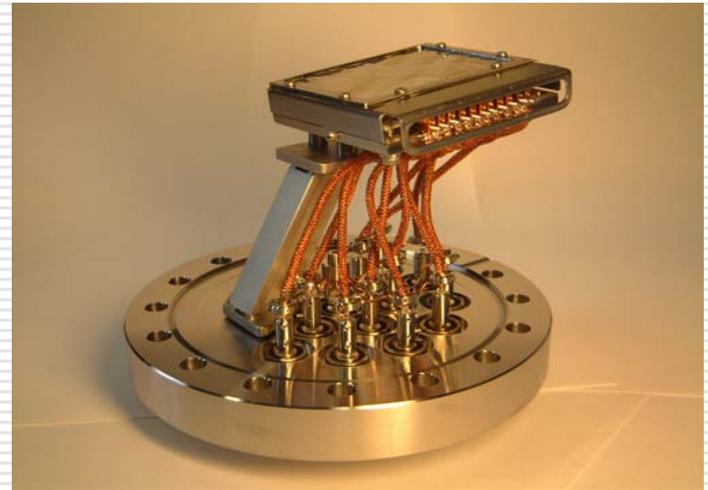
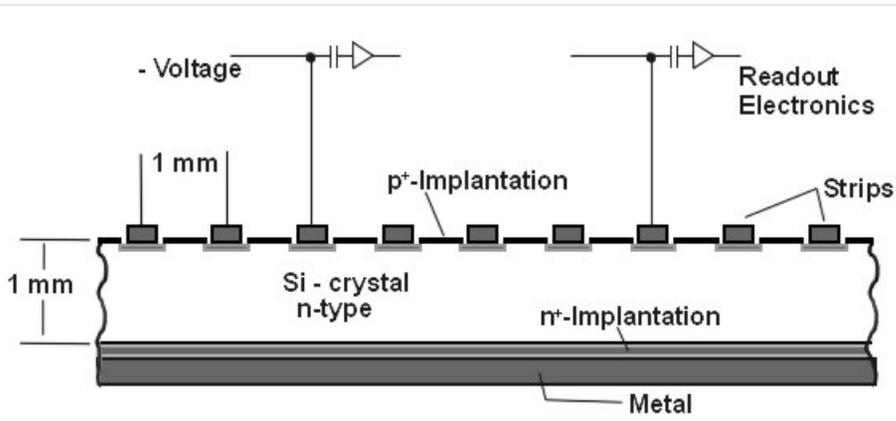
- ⊕ Optimization of the Si detector thickness
 - ⊕ Different distance from the target
 - ⊕ Division of the setup on two parts – for low (up to 25 MeV) and high energy protons
 - ⊕ Different strip pitch (100, 50 μm)
 - ⊕ More detectors in forward part – cover maximum solid angle
 - ⊕ Primary beam of exotic particles
 - ⊕ Different type of experiments
 - ⊕ More optimized setup – end of 2004
-

Detector prototype

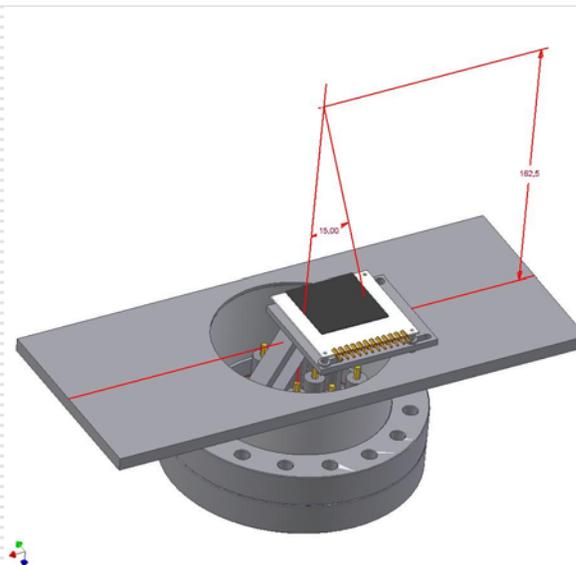


- Active area: $40 \times 40 \text{ mm}^2$
- Thickness: 1 mm
- 40 Strips (Pitch: 1 mm) connected for read-out in groups of 8, each one with two output pins

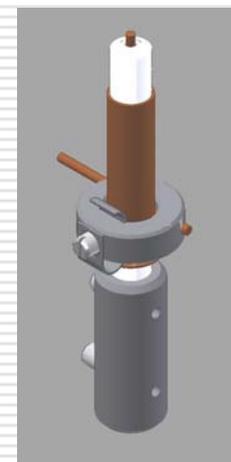
Energy resolution $35 \pm 5 \text{ keV}$ for α -particles with $E = 5.5 \text{ MeV}$



Detector details



Detector in the vacuum chamber of ESR



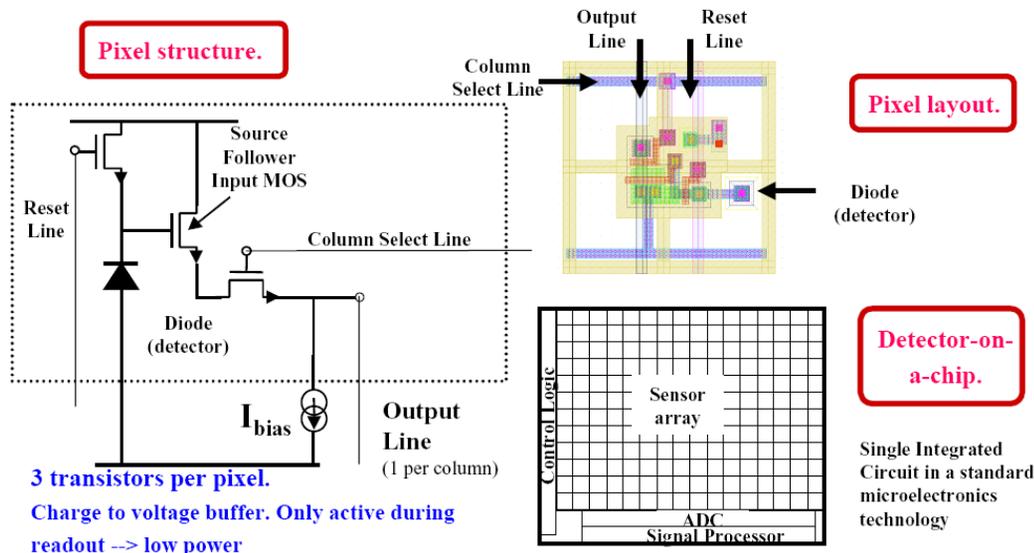
Cabling only
Cu, ceramics

Experiments – next steps

- One UHV compatible Si strip detector installed in the ESR, test beam of ^{12}C – Fall 2004?
 - This detector might be considered as a prototype for the low energy part
 - Setup with more detectors near the internal target and outside the vacuum – feasibility tests during 2005?
 - Investigation of thin detectors – task Nr. 1, possible candidate – Monolithic Active Pixel Sensor (MAPS)
-

Monolithic Active Pixel Sensors

Monolithic Active Pixel Sensors (MAPS).



+ Detector and readout electronics on the same Si crystal

+ Thickness 20 - 50 μm

+ Position resolution - 2 μm

+ Pixel size - up to 10 μm

IReS/LEPSI, IN2P3/ULP, Strasbourg

- Small size

- Slow readout, 1 ms readout now, goal: 50 μs - in 4 years

Si strip & pixel detectors - world experience

- ❑ CMS (LHC) – 24000 sensors, single and double sided, strip detectors, 1 sensor from 6" wafer
 - ❑ CMS (LHC) – pixel detectors 1.6 – 6.4 cm², 44000 pixels per sensor, zero suppression on board
 - ❑ ATLAS (LHC) – 4 layers of silicon tracker + pixel detectors
 - ❑ SLD (SLAC) – central tracking – 3 · 10⁸ pixels
 - ❑ CHICSi UHV detectors - 1 – 1 cm², good energy resolution, no strips
 - ❑ MUST/MUST2 - good energy resolution, strip (not microstrip) detectors, custom electronics, vacuum compatible
-